NSN 5962-01-197-5034



Memory Microcircuit - Page 1 of 2 View Online at https://aerobasegroup.com/nsn/5962-01-197-5034 **Body Length:** 0.990 inches **Body Width:** 0.310 inches **Body Height:** 0.165 inches **Maximum Power Dissipation Rating:** 370.0 milliwatts **Operating Tempurature Range:** +0.0/+70.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **End Application:** 6930llc006290 **Features Provided:** Hermetically sealed and static operation and 3-state output and w/enable **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Output Logic Form:** N-type metal oxide-semiconductor logic **Input Circuit Pattern:** 14 input **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 300.00 nanoseconds propagation delay time, low to high level output and 300.00 nanoseconds propagation delay time, high to low level output **Memory Device Type:** Ram **Memory Capacity:** Unknown **Terminal Type And Quantity:** 20 printed circuit Shelf Life: N/a

Demilitarization: Yes - demil/mli

Unit Of Measure:

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